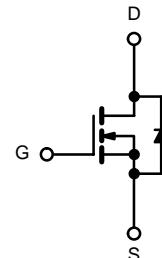


Description

The AO4404 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



N-Channel MOSFET

 $V_{DS} = 30V$ $I_D = 8.5 A$
 $R_{DS(ON)} < 20m\Omega$ @ $V_{GS}=10V$

General Features

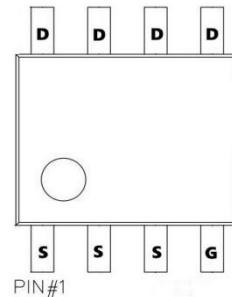
 $V_{DS} = 30V$ $I_D = 8.5 A$
 $R_{DS(ON)} < 20m\Omega$ @ $V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



PIN #1

Absolute Maximum Ratings

 $T_A = 25^\circ C$, unless otherwise noted

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	20	V
Gate-Source Voltage		V_{GS}	± 16	
Continuous Drain Current ($T_J = 150^\circ C$)	$T_C = 25^\circ C$	I_D	12	A
	$T_C = 70^\circ C$		11	
	$T_A = 25^\circ C$		10 ^{b, c}	
	$T_A = 70^\circ C$		8 ^{b, c}	
Pulsed Drain Current		I_{DM}	47	A
Continuous Source-Drain Diode Current	$T_C = 25^\circ C$	I_S	3.7	
	$T_A = 25^\circ C$		2.0 ^{b, c}	
Single Pulse Avalanche Current	$L = 0.1 \text{ mH}$	I_{AS}	20	mJ
Avalanche Energy		E_{AS}	21	
Maximum Power Dissipation	$T_C = 25^\circ C$	P_D	4.1	W
	$T_C = 70^\circ C$		2.5	
	$T_A = 25^\circ C$		2.2 ^{b, c}	
	$T_A = 70^\circ C$		1.3 ^{b, c}	
Operating Junction and Storage Temperature Range		T_J, T_{Stg}	- 55 to 150	°C

Thermal resistance rating

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{b, d}	$t \leq 10 \text{ s}$	R_{thJA}	39	55	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	25	29	

Notes:

- a. Base on $T_C = 25^\circ C$.
- b. Surface Mounted on 1" x 1" FR4 board.
- c. $t = 10 \text{ s}$.
- d. Maximum under Steady State conditions is 85 °C/W.

Specifications $T_J = 25^\circ\text{C}$, unless otherwise noted

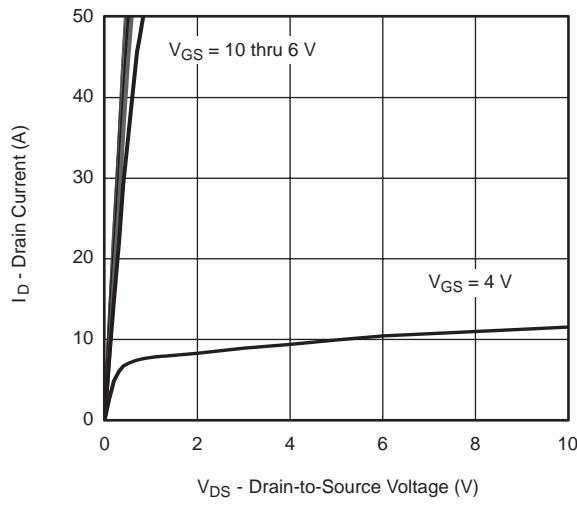
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	20			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250 \mu\text{A}$		26		mV/°C
$V_{GS(\text{th})}$ Temperature Coefficient	$\Delta V_{GS(\text{th})}/T_J$			- 6		
Gate-Source Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	1.0		3.0	V
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
		$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^\circ\text{C}$			10	
On-State Drain Current ^a	$I_{D(\text{on})}$	$V_{DS} \geq 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A
Drain-Source On-State Resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = 10 \text{ V}, I_D = 8 \text{ A}$		13	20	MΩ
		$V_{GS} = 4.5 \text{ V}, I_D = 3 \text{ A}$		19	30	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 10 \text{ V}, I_D = 10 \text{ A}$		50		S
Input Capacitance	C_{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		800		pF
Output Capacitance	C_{oss}			165		
Reverse Transfer Capacitance	C_{rss}			73		
Total Gate Charge	Q_g	$V_{DS} = 10 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$		15	23	nC
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 10 \text{ A}$		6.8	10.2	
Gate-Drain Charge	Q_{gd}			2.5		
Gate Resistance	R_g	$f = 1 \text{ MHz}$	0.36	1.8	3.6	Ω
Turn-On Delay Time	$t_{d(\text{on})}$	$V_{DD} = 10 \text{ V}, R_L = 1.4 \Omega$ $I_D \geq 9 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		16	23	ns
Rise Time	t_r			12	16	
Turn-Off Delay Time	$t_{d(\text{off})}$			16	22	
Fall Time	t_f			10	18	
Turn-On Delay Time	$t_{d(\text{on})}$			8	16	
Rise Time	t_r			10	20	
Turn-Off Delay Time	$t_{d(\text{off})}$			16	22	
Fall Time	t_f			8	15	
Continuous Source-Drain Diode Current	I_S	$T_C = 25^\circ\text{C}$			10	A
Pulse Diode Forward Current ^a	I_{SM}				50	
Body Diode Voltage	V_{SD}	$I_S = 9 \text{ A}$		0.8	1.2	V
Body Diode Reverse Recovery Time	t_{rr}	$I_F = 9 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}, T_J = 25^\circ\text{C}$		15	30	ns
Body Diode Reverse Recovery Charge	Q_{rr}			6	12	nC
Reverse Recovery Fall Time	t_a			8		ns
Reverse Recovery Rise Time	t_b			7		

Notes:

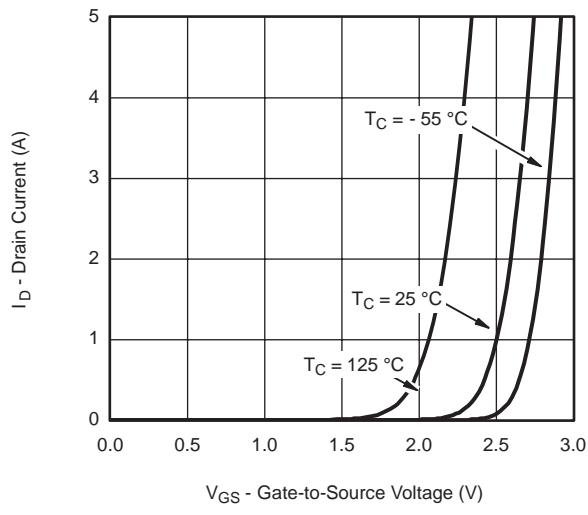
- a. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2 \%$.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

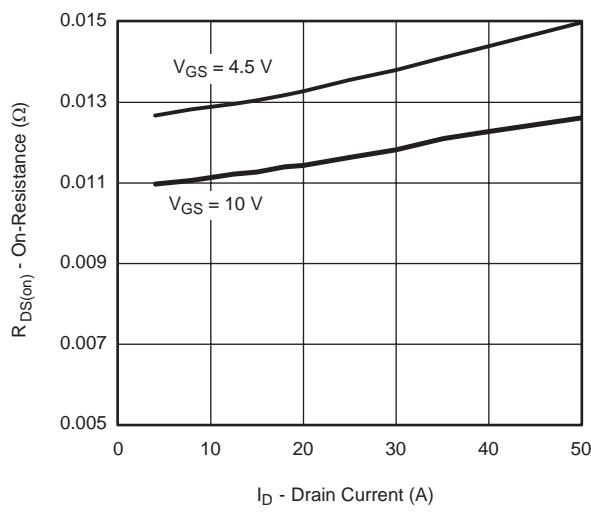
Typical characteristic 25 °C, unless otherwise noted



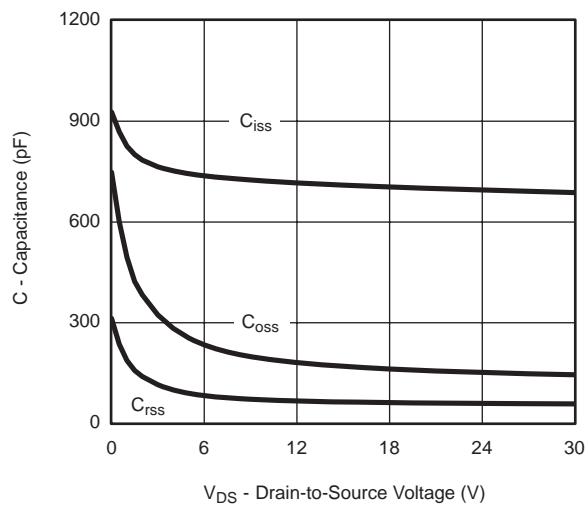
Output Characteristics



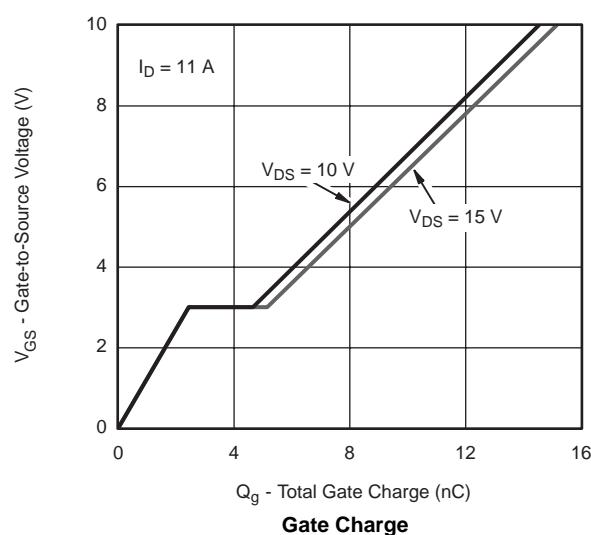
Transfer Characteristics



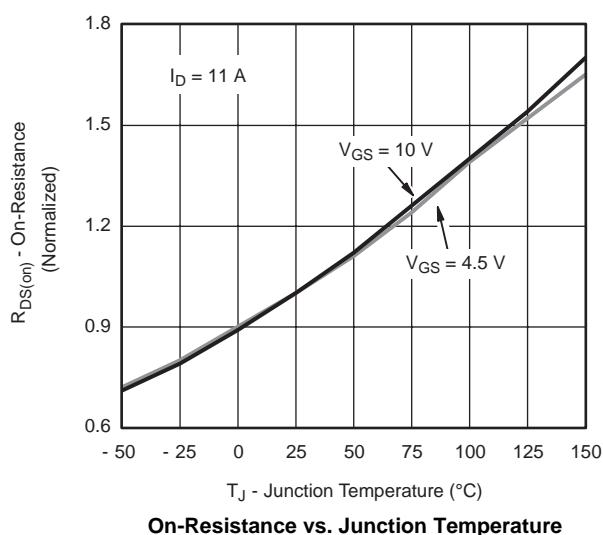
On-Resistance vs. Drain Current and Gate Voltage



Capacitance

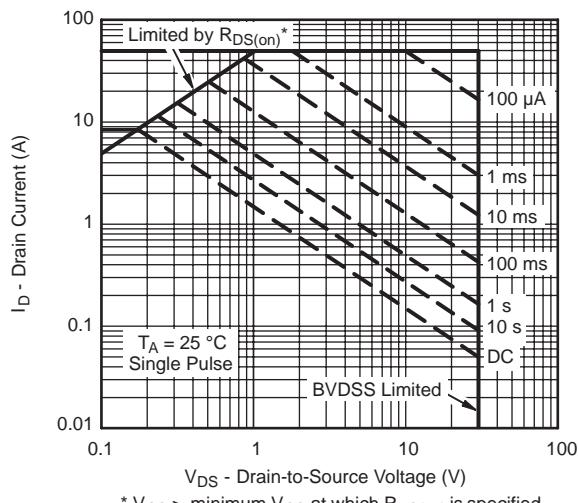
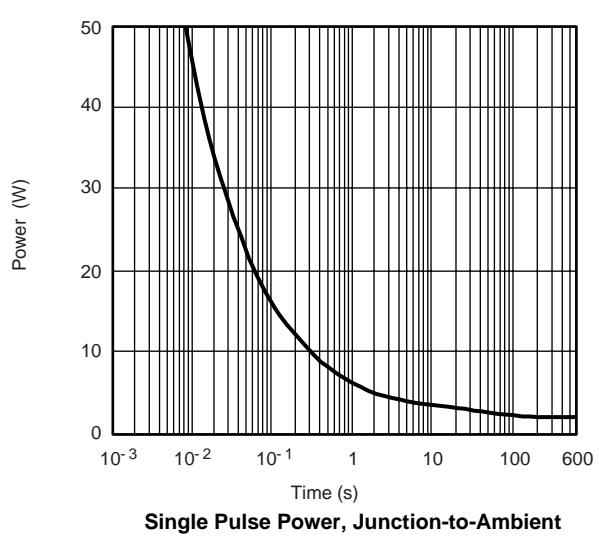
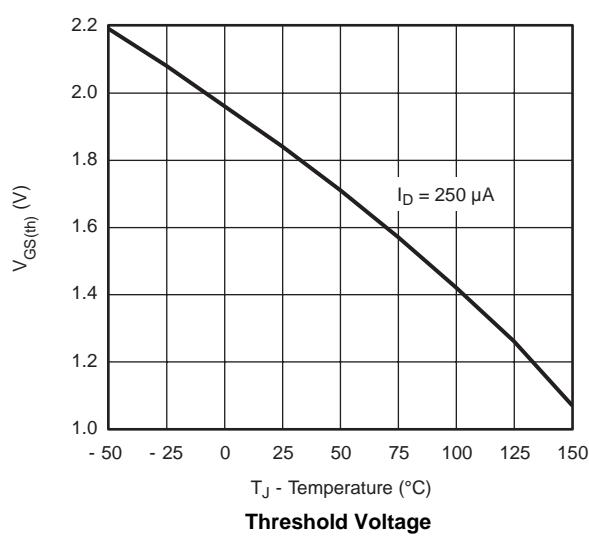
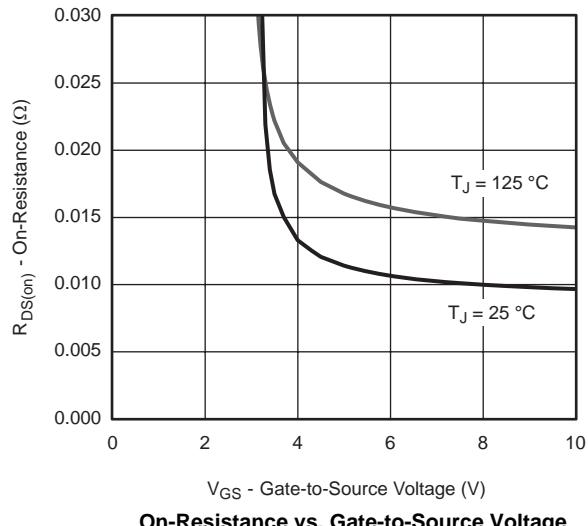
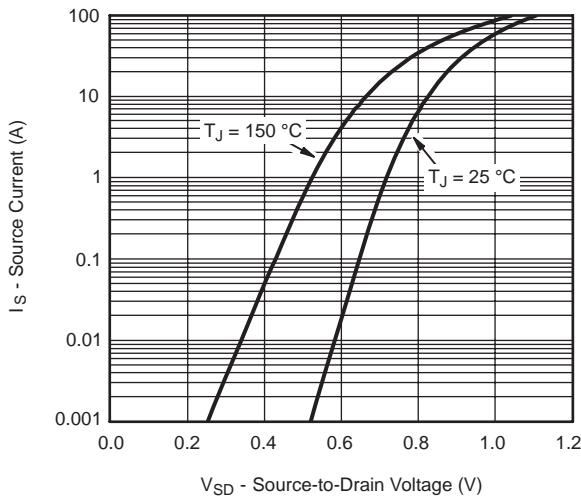


Gate Charge



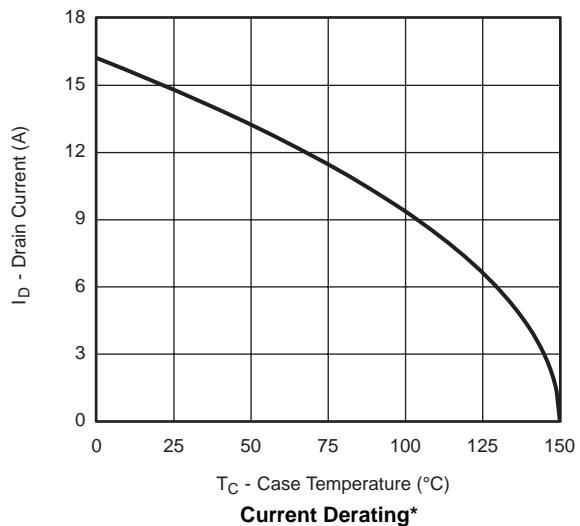
On-Resistance vs. Junction Temperature

Typical characteristic 25 °C, unless otherwise noted

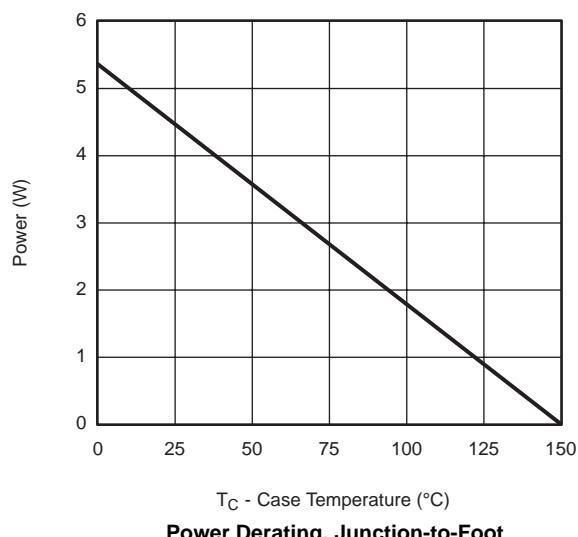


* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

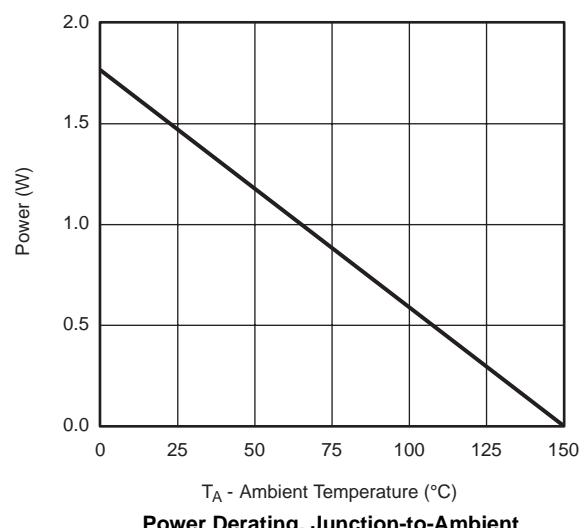
Typical characteristic 25 °C, unless otherwise noted



Current Derating*



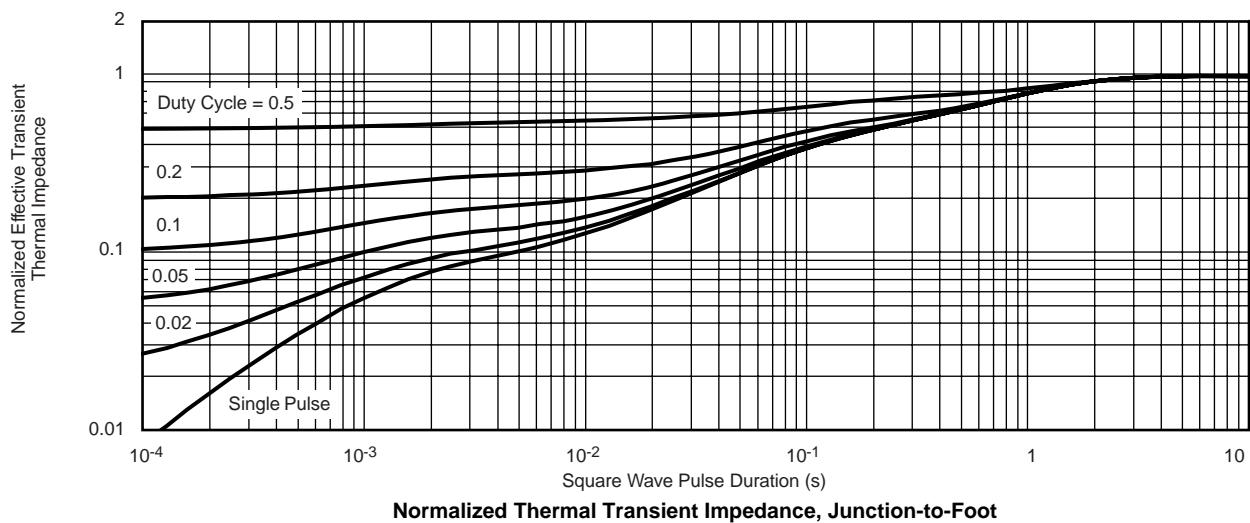
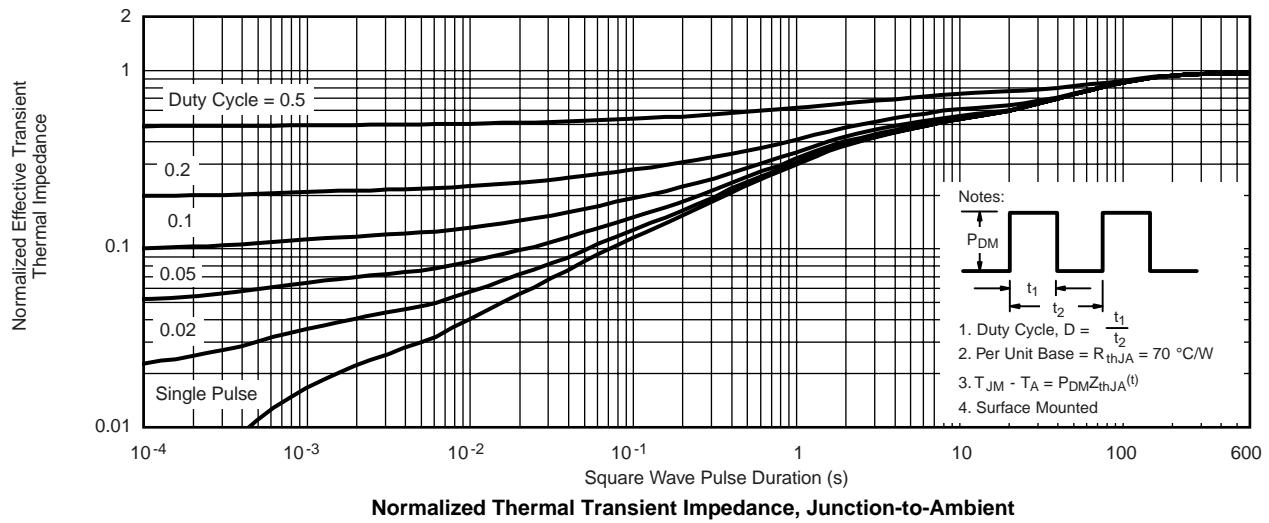
Power Derating, Junction-to-Foot



Power Derating, Junction-to-Ambient

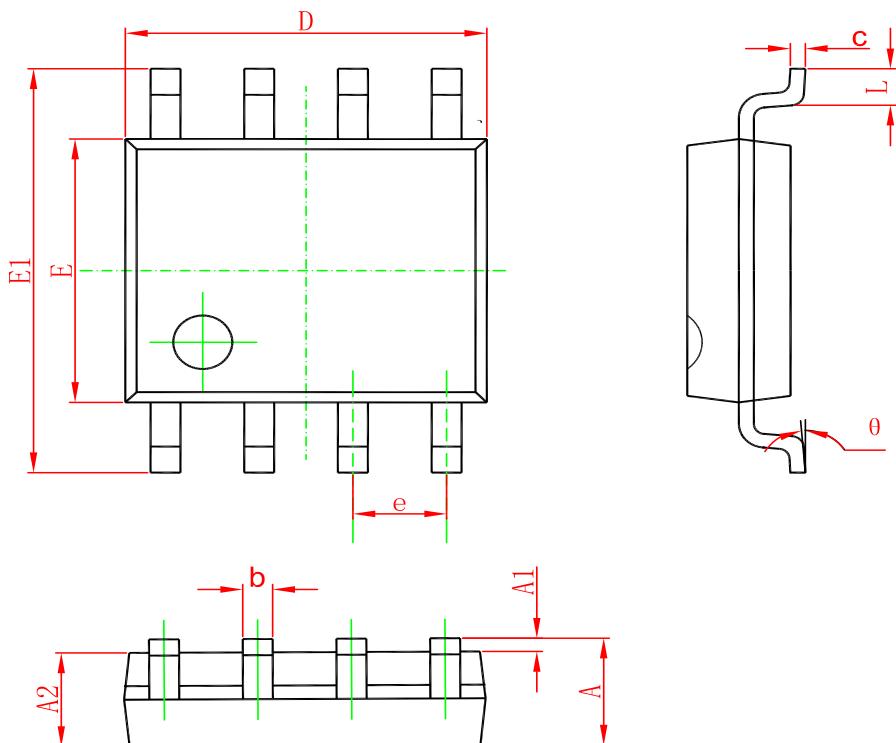
* The power dissipation P_D is based on $T_{J(\max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

Typical characteristic 25 °C, unless otherwise noted



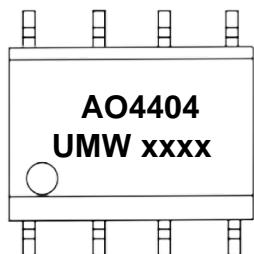
PACKAGE OUTLINE DIMENSIONS

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Marking



("xxxx"代表年份周期)

Ordering information

Order code	Package	Baseqty	Deliverymode
UMW AO4404	SOP-8	3000	Tape and reel